

Dual/Quad SPST, CMOS Analog Switches

HI-200/HI-201 (dual/quad) are monolithic devices comprising independently selectable SPST switches which feature fast switching speeds (HI-200 240ns, and HI-201 185ns) combined with low power dissipation (15mW at 25°C). Each switch provides low "ON" resistance operation for input signal voltage up to the supply rails and for signal current up to 80mA. Rugged DI construction eliminates latch-up and substrate SCR failure modes.

All devices provide break-before-make switching and are TTL and CMOS compatible for maximum application versatility. HI-200/HI-201 are ideal components for use in high frequency analog switching. Typical applications include signal path switching, sample and hold circuit, digital filters, and operational amplifier gain switching networks.

Ordering Information

PART NUMBER	TEMPERATURE RANGE (°C)	PACKAGE	PKG. NO.
HI1-0200-5	0 to 75	14 Ld CERDIP	F14.3
HI2-0200-5	0 to 75	10 Pin Metal Can	T10.B
HI3-0200-5	0 to 75	14 Ld PDIP	E14.3
HI1-0201-2	-55 to 125	16 Ld CERDIP	F16.3
HI1-0201-4	-25 to 85	16 Ld CERDIP	F16.3
HI1-0201-5	0 to 75	16 Ld CERDIP	F16.3
HI3-0201-5	0 to 75	16 Ld PDIP	E16.3
HI4P0201-5	0 to 75	20 Ld PLCC	N20.35
HI9P0201-5	0 to 75	16 Ld SOIC	M16.15
HI9P0201-9	-40 to 85	16 Ld SOIC	M16.15

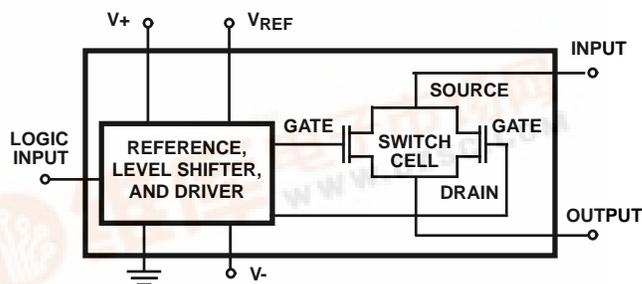
Features

- Analog Voltage Range ±15V
- Analog Current Range 80mA
- Turn-On Time 240ns
- Low r_{ON} 55Ω
- Low Power Dissipation 15mW
- TTL/CMOS Compatible

Applications

- High Frequency Analog Switching
- Sample and Hold Circuits
- Digital Filters
- Operational Amplifier Gain Switching Networks

Functional Diagram



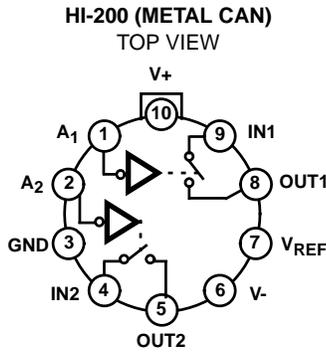
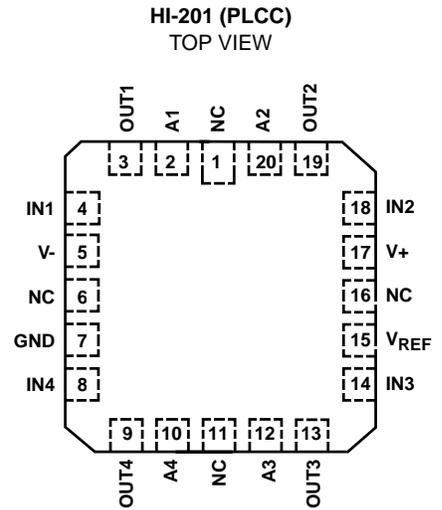
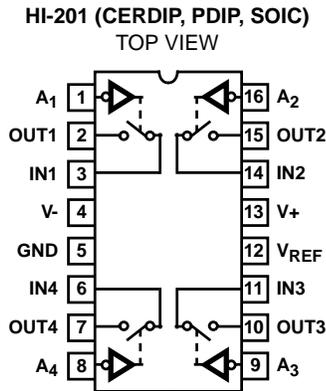
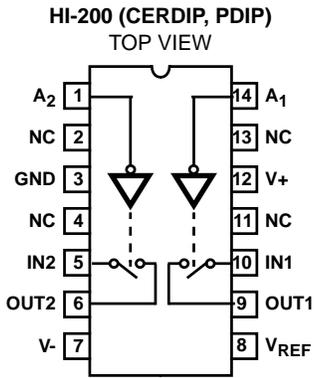
TRUTH TABLE

LOGIC	HI-200	HI-201
0	ON	ON
1	OFF	OFF



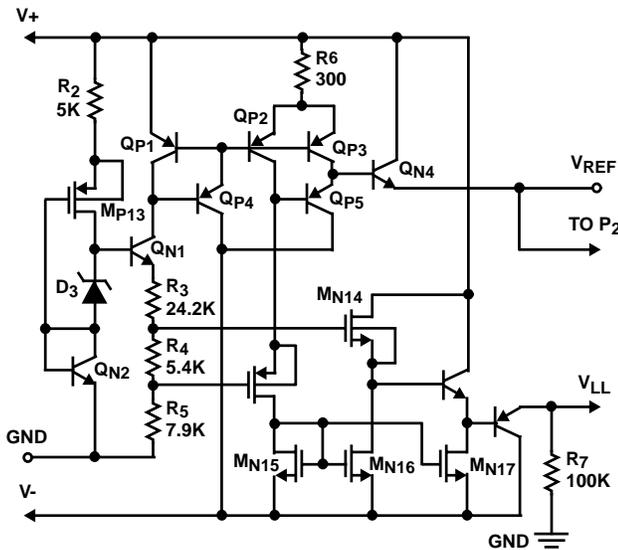
HI-200, HI-201

Pinouts (Switches Shown For Logic "1" Input)

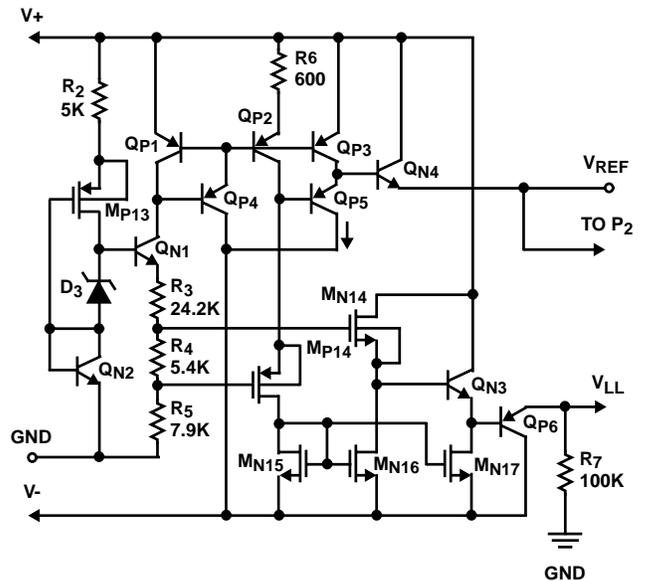


Schematic Diagrams

TTL/CMOS REFERENCE CIRCUIT V_{REF} CELL
HI-200



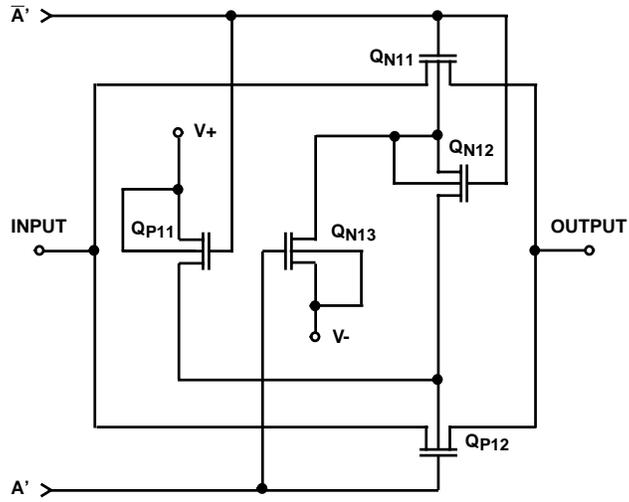
TTL/CMOS REFERENCE CIRCUIT V_{REF} CELL
HI-201



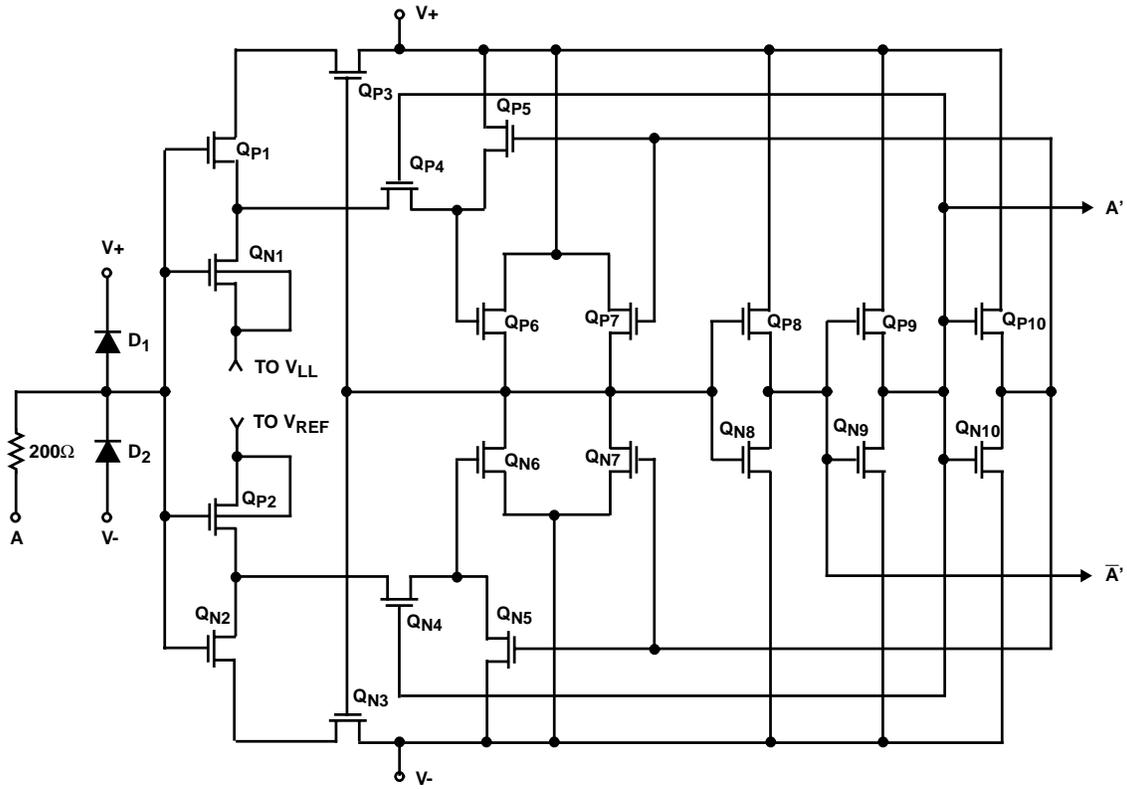
HI-200, HI-201

Schematic Diagrams (Continued)

SWITCH CELL



DIGITAL INPUT BUFFER AND LEVEL SHIFTER



HI-200, HI-201

Absolute Maximum Ratings

Supply Voltage (V+ to V-)	44V (±22)
V _{REF} to Ground	20V, -5V
Digital Input Voltage	(V+) +4V to (V-) -4V
Analog Input Voltage (One Switch)	(V+) +2V to (V-) -2V

Operating Conditions

Temperature Ranges	
HI-201-2	-55°C to 125°C
HI-201-4	-25°C to 85°C
HI-200-5, HI-201-5	0°C to 75°C
HI-201-9	-40°C to 85°C

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
14 Ld CERDIP Package	80	24
16 Ld CERDIP Package	75	20
PLCC Package	80	N/A
PDIP Package	95	N/A
16 Ld SOIC Package	110	N/A
10 Pin Metal Can Package	160	75
Maximum Storage Temperature	-65°C to 150°C	
Maximum Junction Temperature (Hermetic Packages)	175°C	
Maximum Junction Temperature (Plastic Packages)	150°C	
Maximum Lead Temperature (Soldering, 10s)	300°C (PLCC and SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications

Supplies = +15V, -15V; V_{REF} = Open; V_{AH} (Logic Level High) = 2.4V, V_{AL} (Logic Level Low) = 0.8V

PARAMETER	TEST CONDITIONS	TEMP (°C)	-2			-4, -5, -9			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
DYNAMIC CHARACTERISTICS									
Switch ON Time, t _{ON}									
HI-200		25	-	240	500	-	240	-	ns
HI-201		25	-	185	500	-	185	-	ns
		Full	-	1000	-	-	1000	-	ns
Switch OFF Time, t _{OFF}									
HI-200		25	-	330	500	-	500	-	ns
HI-201		25	-	220	500	-	220	-	ns
		Full	-	1000	-	-	1000	-	ns
Off Isolation	(Note 4)								
HI-200		25	-	70	-	-	70	-	dB
HI-201		25	-	80	-	-	80	-	dB
Input Switch Capacitance, C _{S(OFF)}		25	-	5.5	-	-	5.5	-	pF
Output Switch Capacitance, C _{D(OFF)}		25	-	5.5	-	-	5.5	-	pF
Output Switch Capacitance, C _{D(ON)}		25	-	11	-	-	11	-	pF
Digital Input Capacitance, C _A		25	-	5	-	-	5	-	pF
Drain-to-Source Capacitance, C _{DS(OFF)}		25	-	0.5	-	-	0.5	-	pF
DIGITAL INPUT CHARACTERISTICS									
Input Low Threshold, V _{AL}		Full	-	-	0.8	-	-	0.8	V
Input High Threshold, V _{AH}		Full	2.4	-	-	2.4	-	-	V
Input Leakage Current (High or Low), I _A	(Note 3)	Full	-	-	1.0	-	-	1.0	μA
ANALOG SWITCH CHARACTERISTICS									
Analog Signal Range, V _S		Full	-15	-	+15	-15	-	+15	V
ON Resistance, r _{ON}	(Note 2)	25	-	55	70	-	55	80	Ω
		Full	-	80	100	-	72	100	Ω

HI-200, HI-201

Electrical Specifications Supplies = +15V, -15V; V_{REF} = Open; V_{AH} (Logic Level High) = 2.4V, V_{AL} (Logic Level Low) = 0.8V **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP (°C)	-2			-4, -5, -9			UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX		
OFF Input Leakage Current, I _{S(OFF)}	(Note 6)	25	-	1	5	-	1	50	nA	
		HI-200	Full	-	100	500	-	10	500	nA
		HI-201	25	-	2	5	-	2	50	nA
		Full	-	-	500	-	-	250	nA	
OFF Output Leakage Current, I _{D(OFF)}	(Note 6)	25	-	1	5	-	1	50	nA	
		HI-200	Full	-	100	500	-	10	500	nA
		HI-201	25	-	2	5	-	2	50	nA
		Full	-	35	500	-	35	250	nA	
ON Leakage Current, I _{D(ON)}	(Note 6)	25	-	1	5	-	1	50	nA	
		HI-200	Full	-	100	500	-	10	500	nA
		HI-201	25	-	2	5	-	2	50	nA
		Full	-	-	500	-	-	250	nA	
POWER SUPPLY CHARACTERISTICS (Note 5)										
Power Dissipation, P _D		25	-	15	-	-	15	-	mW	
		Full	-	-	60	-	-	60	mW	
Current, I ₊		25	-	0.5	-	-	0.5	-	mA	
		Full	-	-	2.0	-	-	2.0	mA	
Current, I ₋		25	-	0.5	-	-	0.5	-	mA	
		Full	-	-	2.0	-	-	2.0	mA	

NOTES:

2. V_{OUT} = ±10V, I_{OUT} = 1mA.
3. Digital Inputs are MOS gates: typical leakage is < 1nA.
4. V_A = 5V, R_L = 1kΩ, C_L = 10pF, V_S = 3V_{RMS}, f = 100kHz.
5. V_A = +3V or V_A = 0V for Both Switches.
6. Refer to Leakage Current Measurements (Figure 2).

Test Circuits and Waveforms T_A = 25°C, V_{SUPPLY} = ±15V, V_{AH} = 2.4V, V_{AL} = 0.8V and V_{REF} = Open

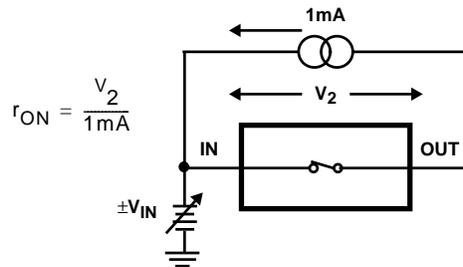


FIGURE 1A. ON RESISTANCE TEST CIRCUIT

HI-200, HI-201

Test Circuits and Waveforms $T_A = 25^\circ\text{C}$, $V_{\text{SUPPLY}} = \pm 15\text{V}$, $V_{\text{AH}} = 2.4\text{V}$, $V_{\text{AL}} = 0.8\text{V}$ and $V_{\text{REF}} = \text{Open}$ (Continued)

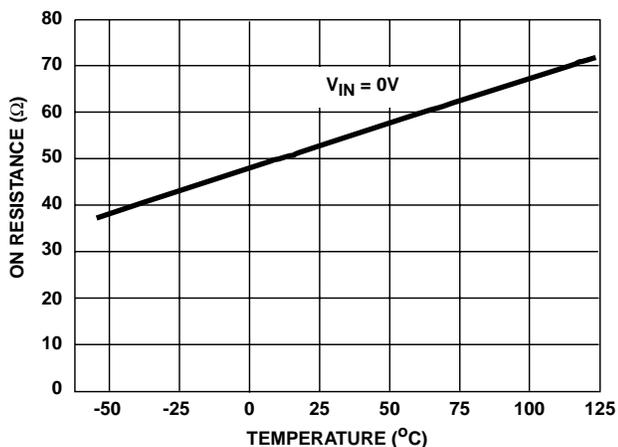


FIGURE 1B. ON RESISTANCE vs TEMPERATURE

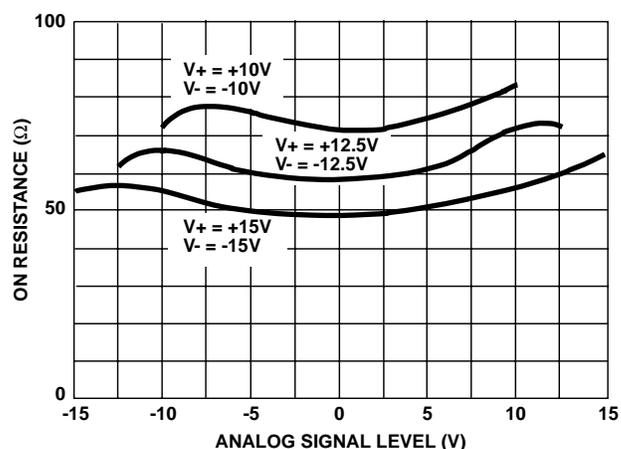


FIGURE 1C. HI-200 ON RESISTANCE vs ANALOG SIGNAL LEVEL

FIGURE 1. ON RESISTANCE

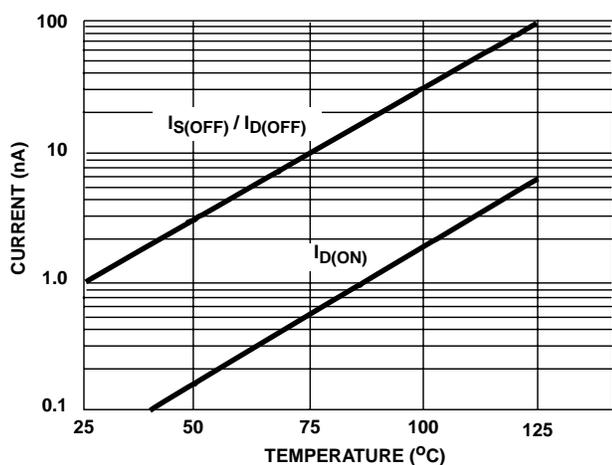


FIGURE 2A. LEAKAGE CURRENT vs TEMPERATURE

FIGURE 2. LEAKAGE CURRENTS

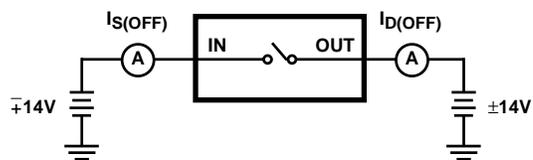


FIGURE 2B. OFF LEAKAGE CURRENT TEST CIRCUIT

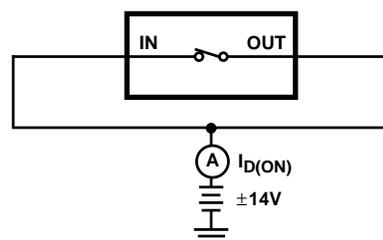


FIGURE 2C. ON LEAKAGE CURRENT TEST CIRCUIT

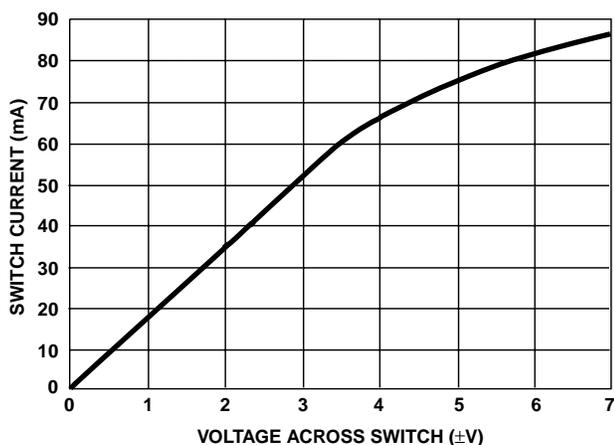


FIGURE 3A. SWITCH CURRENT vs VOLTAGE

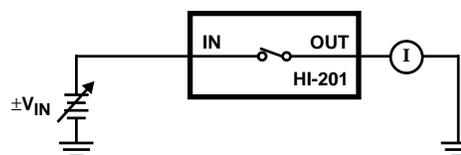


FIGURE 3B. TEST CIRCUIT

FIGURE 3. SWITCH CURRENT

HI-200, HI-201

Test Circuits and Waveforms $T_A = 25^\circ\text{C}$, $V_{\text{SUPPLY}} = \pm 15\text{V}$, $V_{\text{AH}} = 2.4\text{V}$, $V_{\text{AL}} = 0.8\text{V}$ and $V_{\text{REF}} = \text{Open}$ (Continued)

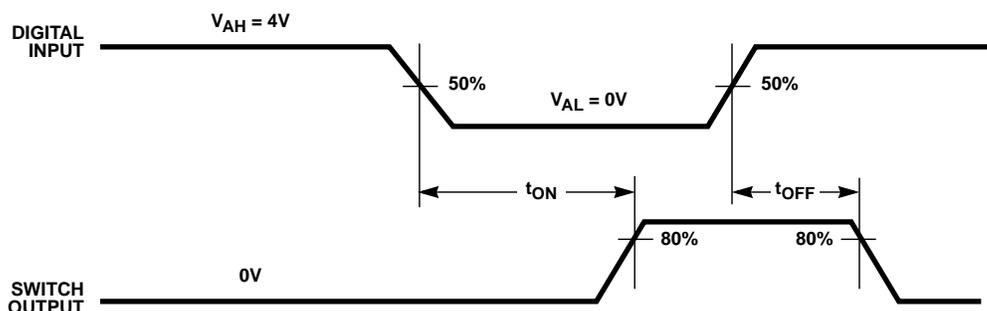
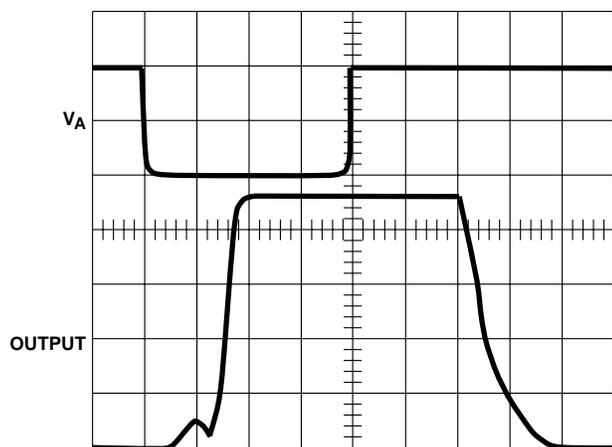
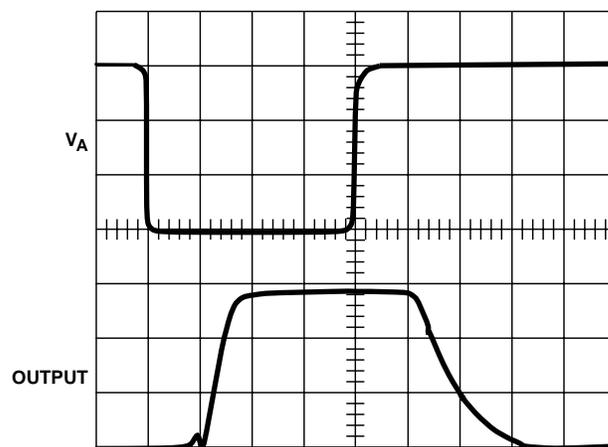


FIGURE 4A. MEASUREMENT POINTS



$V_A = 0$ to 4V
Vertical: 2V/Div .
Horizontal: 100ns/Div .

FIGURE 4B. WAVEFORMS WITH TTL COMPATIBLE LOGIC INPUT



$V_A = 0$ to 15V
Vertical: 5V/Div .
Horizontal: 100ns/Div .

FIGURE 4C. WAVEFORMS WITH CMOS COMPATIBLE LOGIC INPUT

FIGURE 4. SWITCH t_{ON} AND t_{OFF}

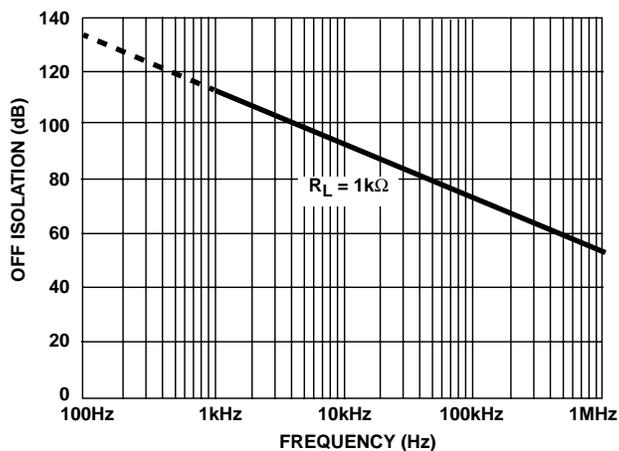


FIGURE 5. HI-201 OFF ISOLATION vs FREQUENCY

For more information see Application Notes AN520, AN521, AN531, AN532 and AN557.

Application Information

Single Supply Operation

The switch operation of the HI-200/201 is dependent upon an internally generated switching threshold voltage optimized for $\pm 15V$ power supplies. The HI-200/201 does not provide the necessary internal switching threshold in a single supply system. Therefore, if single supply operation is required, the HI-300 series of switches is recommended. The HI-300 series will remain operational to a minimum +5V single supply.

Switch performance will degrade as power supply voltage is reduced from optimum levels ($\pm 15V$). So it is recommended that a single supply design be thoroughly evaluated to ensure that the switch will meet the requirements of the application.

For further information see Application Notes AN520, AN521, AN531, AN532, AN543 and AN557.

HI-200

Die Characteristics

DIE DIMENSIONS:

54 mils x 79 mils

METALLIZATION:

Type: CuAl
Thickness: $16\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

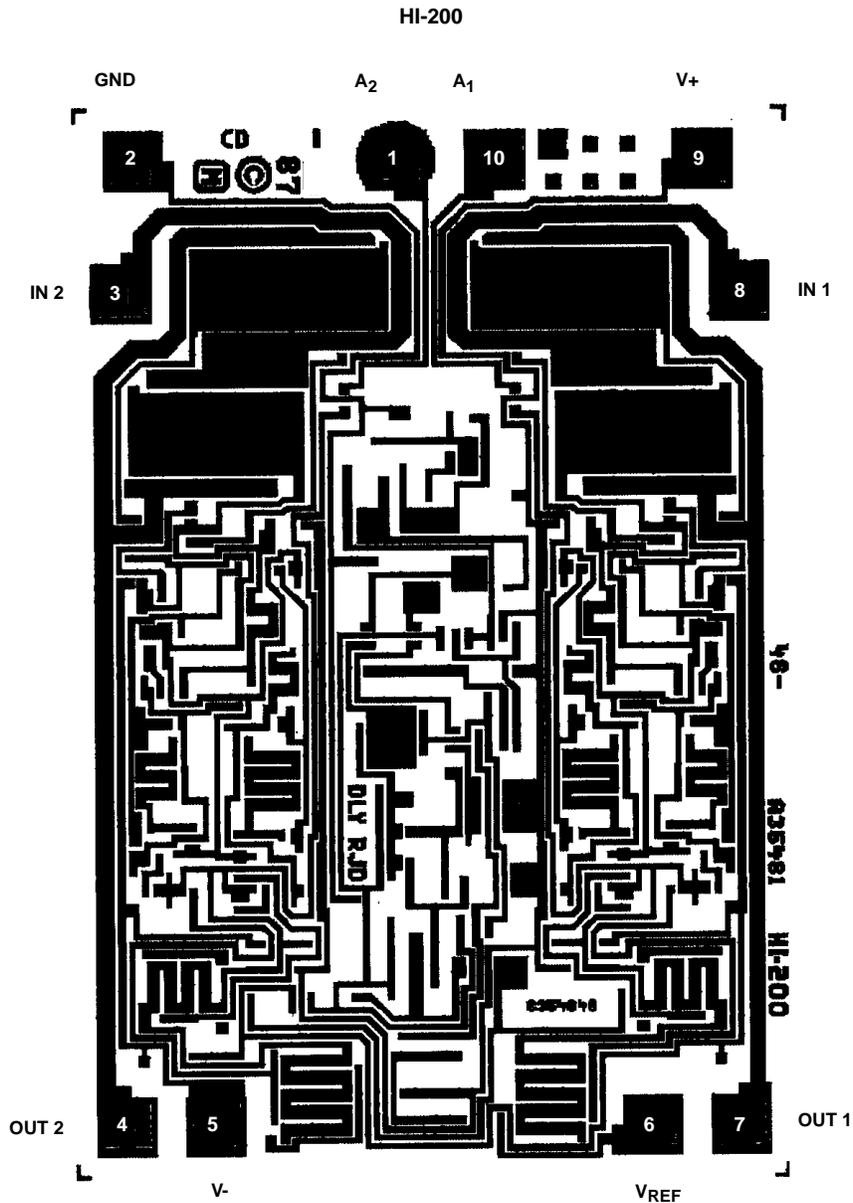
PASSIVATION:

Type: Nitride over Silox
Nitride Thickness: $3.5\text{k}\text{\AA} \pm 1\text{k}\text{\AA}$
Silox Thickness: $12\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

WORST CASE CURRENT DENSITY:

$2 \times 10^5 \text{ A/cm}^2$ at 25mA

Metallization Mask Layout



HI-201

Die Characteristics

DIE DIMENSIONS:

81 mils x 85 mils

METALLIZATION:

Type: CuAl

Thickness: $16\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

PASSIVATION:

Type: Nitride over Silox

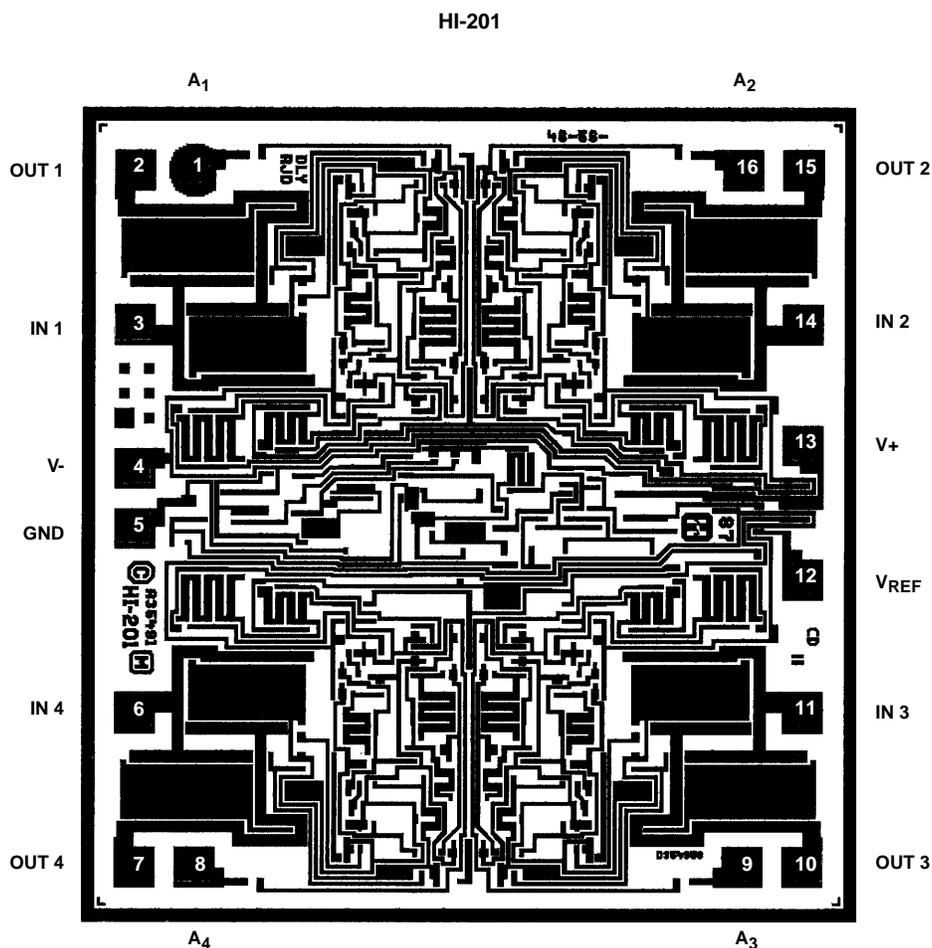
Nitride Thickness: $3.5\text{k}\text{\AA} \pm 1\text{k}\text{\AA}$

Silox Thickness: $12\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

WORST CASE CURRENT DENSITY:

$2 \times 10^5 \text{ A/cm}^2$ at 25mA

Metallization Mask Layout



All Intersil semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

Intersil semiconductor products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see web site <http://www.intersil.com>

Sales Office Headquarters

NORTH AMERICA

Intersil Corporation
P. O. Box 883, Mail Stop 53-204
Melbourne, FL 32902
TEL: (407) 724-7000
FAX: (407) 724-7240

EUROPE

Intersil SA
Mercure Center
100, Rue de la Fusee
1130 Brussels, Belgium
TEL: (32) 2.724.2111
FAX: (32) 2.724.22.05

ASIA

Intersil (Taiwan) Ltd.
7F-6, No. 101 Fu Hsing North Road
Taipei, Taiwan
Republic of China
TEL: (886) 2 2716 9310
FAX: (886) 2 2715 3029